

SMAF Plastic-Encapsulate Diodes

Features:

- $I_{F(AV)}$ 1A
- V_{RRM} 50V-600V
- High surge current capability
- Polarity: Color band denotes cathode

Applications:

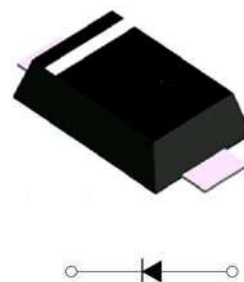
- Rectifier

Marking

- ES1XF

X : From A To J

SMAF



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	ES1							
				AF	BF	CF	DF	EF	GF	HF	JF
Repetitive Peak Reverse Voltage	V_{RRM}	V		50	100	150	200	300	400	500	600
Maximum RMS Voltage	V_{RMS}	V		35	70	105	140	210	280	350	420
Average Forward Current	$I_{F(AV)}$	A	60Hz Half-sine wave, Resistance load, $T_L=120^{\circ}\text{C}$	1.0							
Surge(Non-repetitive) Forward Current	I_{FSM}	A	60Hz Half-sine wave, 1 cycle, $T_a=25^{\circ}\text{C}$	30							
Operation Junction and Storage Temperature Range	T_J, T_{STG}	$^{\circ}\text{C}$		-55 ~ +150							

Electrical Characteristics ($T=25^{\circ}\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition		ES1							
					AF	BF	CF	DF	EF	GF	HF	JF
Peak Forward Voltage	V _F	V	I _F =1.0A		0.95				1.25		1.70	
Maximum reverse recovery time	t _{rr}	ns	I _F =0.5A,I _R =1.0A,I _{rr} =0.25A		35							
Peak Reverse Current	I _{RRM1}	μA	V _{RM} =V _{RRM}	T _a =25℃	5							
	T _a =100℃			100								
Thermal Resistance(Typical)	R _{θJ-A}	℃/W	Between junction and ambient		85							
	R _{θJ-L}		Between junction and terminal		35							

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

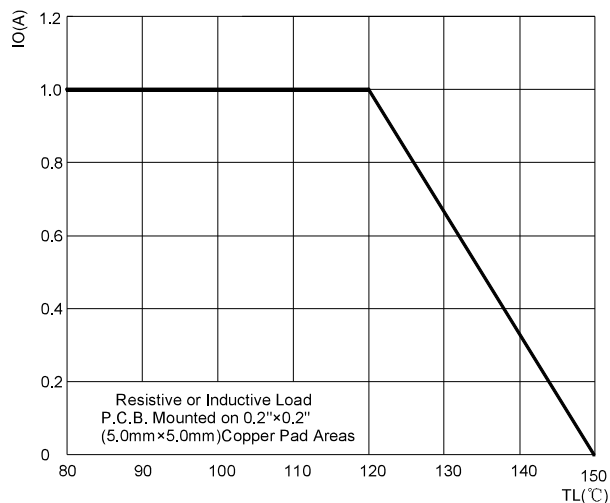


FIG.2: MAXIMUM NON-REPETITIVE FORWARD URGE CURRENT

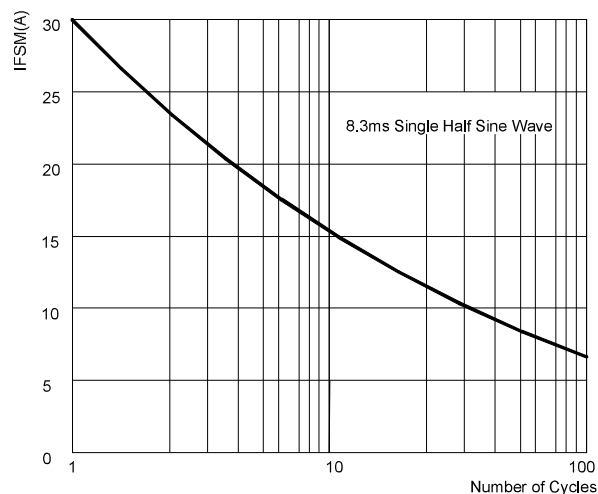


FIG.3: TYPICAL FORWARD CHARACTERISTICS

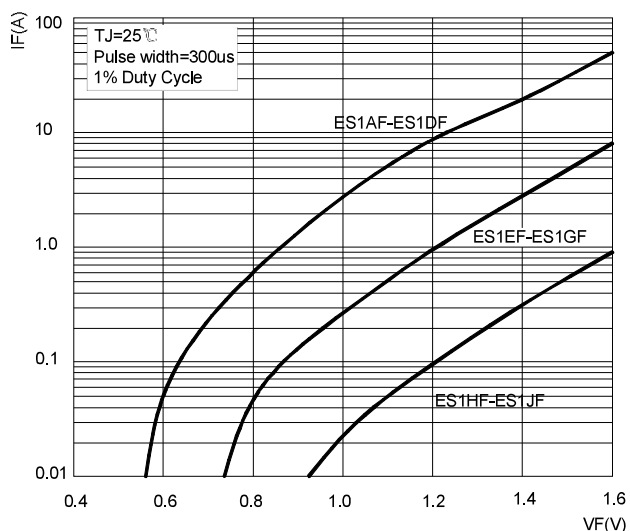


FIG.4: TYPICAL REVERSE CHARACTERISTICS

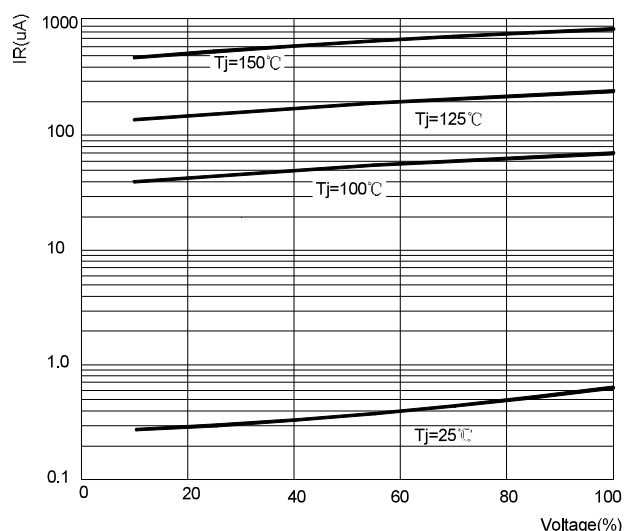
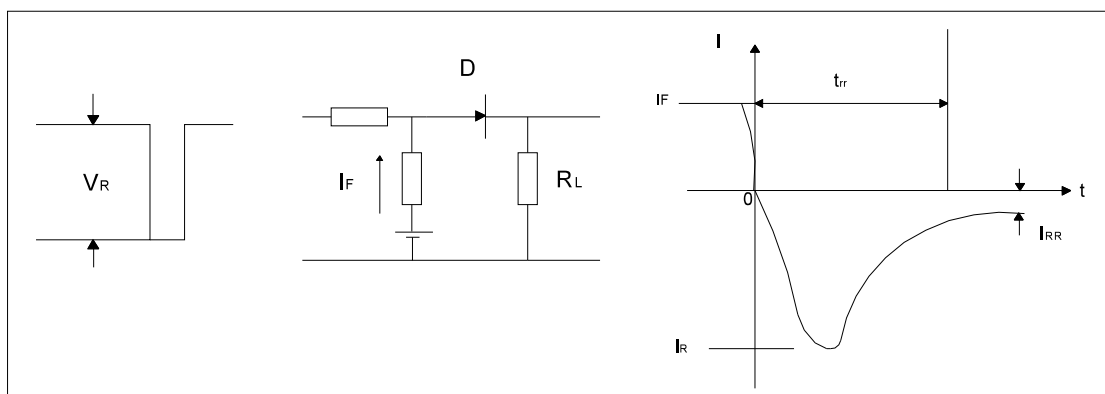
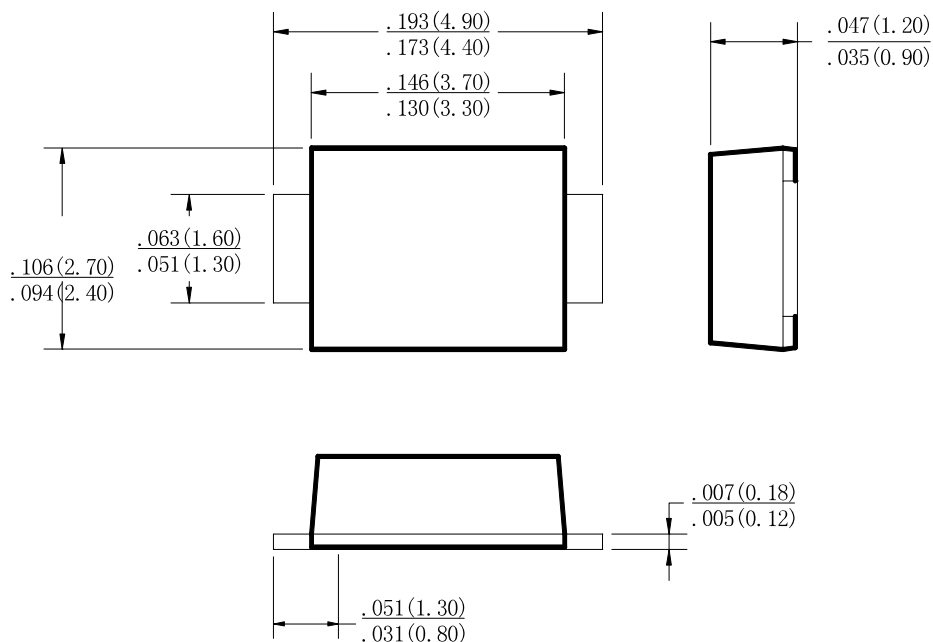


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

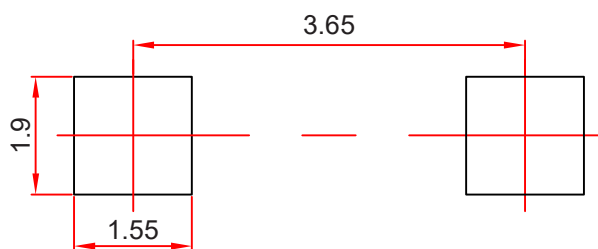


SMAF Package Outline Dimensions



Dimensions in inches and (millimeters)

SMAF Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

Reel Taping Specifications For Surface Mount Devices- SMAF

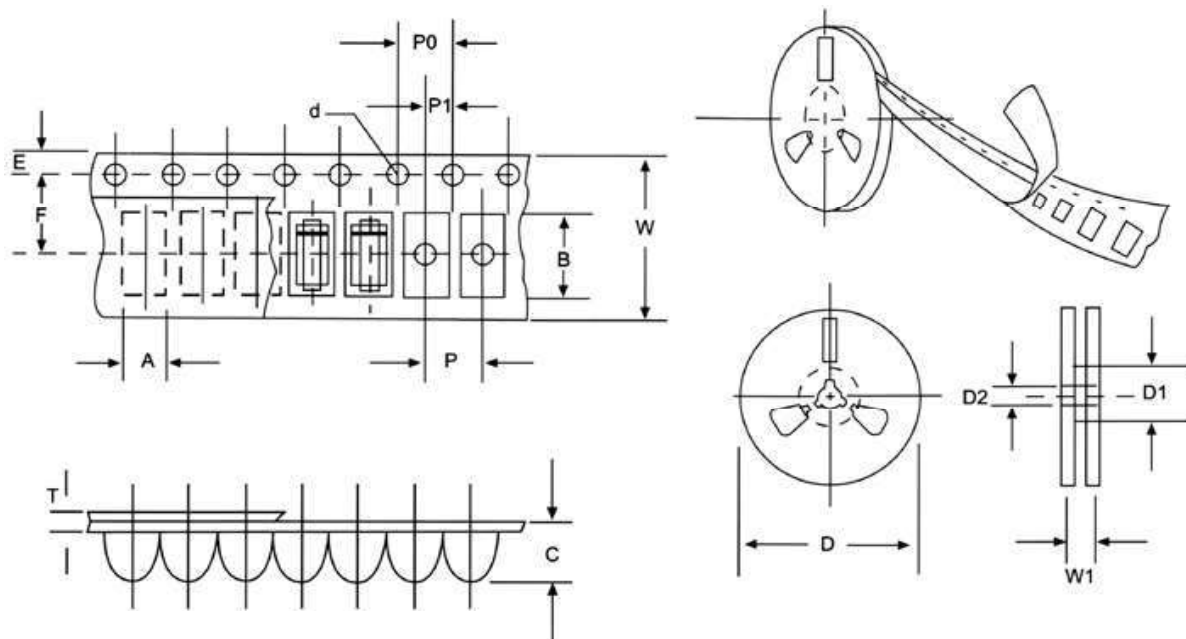


FIG:CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING

ITEM	SYMBOL	SMAF mm(inch)
Carrier width	A	2.83+0.1(0.112+0.004)
Carrier length	B	4.90+0.1(0.193+0.004)
Carrier depth	C	1.45+0.1(0.057+0.004)
Sprocket hole	d	1.55+0.05(0.061+0.002)
Reel outside diameter	D	178+2.0(7.0+0.079)
Reel inner diameter	D1	54±1.0(2.13±0.039)
Feed hole diameter	D2	13+0.5(0.512+0.020)
Sprocket hole position	E	1.75+0.1(0.069+0.004)
Punch hole position	F	5.5+0.05(0.217+0.002)
Punch hole pitch	P	4.0+0.1(0.157+0.004)
Sprocket hole pitch	P0	4.0+0.1(0.157+0.004)
Embossment center	P1	2.0+0.1(0.079+0.004)
Total tape thickness	T	0.23-0.29(0.009-0.011)
Tape width	W	12.0+0.1(0.472+0.004)
Reel width	W1	16.8+2.0(0.661+0.079)

NOTE: Devices are packed in accordance with EIA standard RS-481-A and specification given above.